



THE DATASHEET OF 3BR0665JZ



CoolSET[®]-F3R

ICE3BR0665J

Off-Line SMPS Current Mode
Controller with integrated 650V
CoolMOS[®] and Startup cell
(frequency jitter Mode) in DIP-8

Power Management & Supply



Never stop thinking.

CoolSET®-F3R

ICE3BR0665J

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Datasheet

Previous Version: 2.2

Page	Subjects (major changes since last revision)
27	revised outline dimension for PG-DIP-8 package

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Off-Line SMPS Current Mode Controller with integrated 650V CoolMOS[®] and Startup cell (frequency jitter Mode) in DIP-8

Product Highlights

- Active Burst Mode to reach the lowest Standby Power Requirements < 50mW
- Auto Restart protection for overload, overtemperature, overvoltage
- External auto-restart enable function
- Built-in soft start and blanking window
- Extendable blanking Window for high load jumps
- Built-in frequency jitter and soft driving for low EMI
- Green Mould Compound
- Pb-free lead plating; RoHS compliant

Features

- 650V avalanche rugged CoolMOS[®] with built-in Startup Cell
- Active Burst Mode for lowest Standby Power
- Fast load jump response in Active Burst Mode
- 65kHz internally fixed switching frequency
- Auto Restart Protection Mode for Overload, Open Loop, VCC Undervoltage, Overtemperature & Overvoltage
- Built-in Soft Start
- Built-in blanking window with extendable blanking time for short duration high current
- External auto-restart enable pin
- Max Duty Cycle 75%
- Overall tolerance of Current Limiting < $\pm 5\%$
- Internal PWM Leading Edge Blanking
- BiCMOS technology provide wide VCC range
- Built-in Frequency jitter and soft driving for low EMI

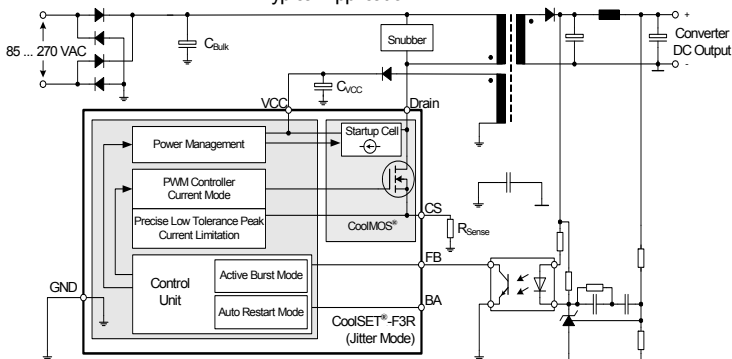
Description

The CoolSET[®]-F3R jitter series (ICE3BRxx65J) is the latest version of CoolSET[®]-F3. It targets for the Off-Line battery adapters and low cost SMPS for lower power range such as application for DVD R/W, DVD Combi, Blue ray DVD player, set top box, etc. Besides inherited the outstanding performance of the CoolSET[®]-F3 in the BiCMOS technology, active burst mode, auto-restart protection, propagation delay compensation, etc., CoolSET[®]-F3R series has some new features such as built-in soft start time, built-in blanking window, built-in frequency jitter, soft gate driving, etc. In case a longer blanking time is needed for high load application, a simple addition of capacitor to BA pin can serve the purpose. Furthermore, an external auto-restart enable feature can provide extra protection when there is a need of immediate stop of power switching.



PG-DIP-8

Typical Application



Type	Package	Marking	V _{DS}	F _{osc}	R _{DS(on)} ¹⁾	230VAC $\pm 15\%$ ²⁾	85-265 VAC ²⁾
ICE3BR0665J	PG-DIP-8	ICE3BR0665J	650V	65kHz	0.65	74W	49W

¹⁾ typ @ T_J=25°C

²⁾ Calculated maximum input power rating at T_a=50°C, T_J=125°C and without copper area as heat sink. Refer to input power curve for other T_a.

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Pin Configuration and Functionality

1 Pin Configuration and Functionality

1.1 Pin Configuration with PG-DIP-8

Pin	Symbol	Function
1	BA	extended Blanking & Auto-restart
2	FB	FeedBack
3	CS	Current Sense/ 650V ¹⁾ CoolMOS® Source
4	Drain	650V ¹⁾ CoolMOS® Drain
5	Drain	650V ¹⁾ CoolMOS® Drain
6	n.c.	Not connected
7	VCC	Controller Supply Voltage
8	GND	Controller GrouND

¹⁾ at T_J=110°C

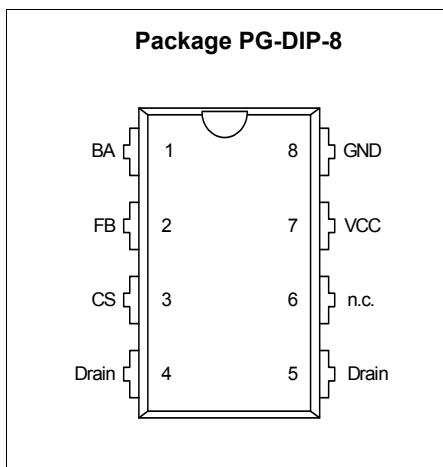


Figure 1 Pin Configuration PG-DIP-8 (top view)

Note: Pin 4 and 5 are shorted

1.2 Pin Functionality

BA (extended Blanking & Auto-restart)

The BA pin combines the functions of extendable blanking time for over load protection and the external auto-restart enable. The extendable blanking time function is to extend the built-in 20 ms blanking time by adding an external capacitor at BA pin to ground. The external auto-restart enable function is an external access to stop the gate switching and force the IC enter auto-restart mode. It is triggered by pulling down the BA pin to less than 0.33V.

FB (Feedback)

The information about the regulation is provided by the FB Pin to the internal Protection Unit and to the internal PWM-Comparator to control the duty cycle. The FB-Signal is the only control signal in case of light load at the Active Burst Mode.

CS (Current Sense)

The Current Sense pin senses the voltage developed on the series resistor inserted in the source of the integrated CoolMOS®. If voltage in CS pin reaches the internal threshold of the Current Limit Comparator, the Driver output is immediately switched off. Furthermore the current information is provided for the PWM-Comparator to realize the Current Mode.

Drain (Drain of integrated CoolMOS®)

Drain pin is the connection to the Drain of the integrated CoolMOS®.

VCC (Power Supply)

VCC pin is the positive supply of the IC. The operating range is between 10.5V and 25V.

GND (Ground)

GND pin is the ground of the controller.

2 Representative Blockdiagram

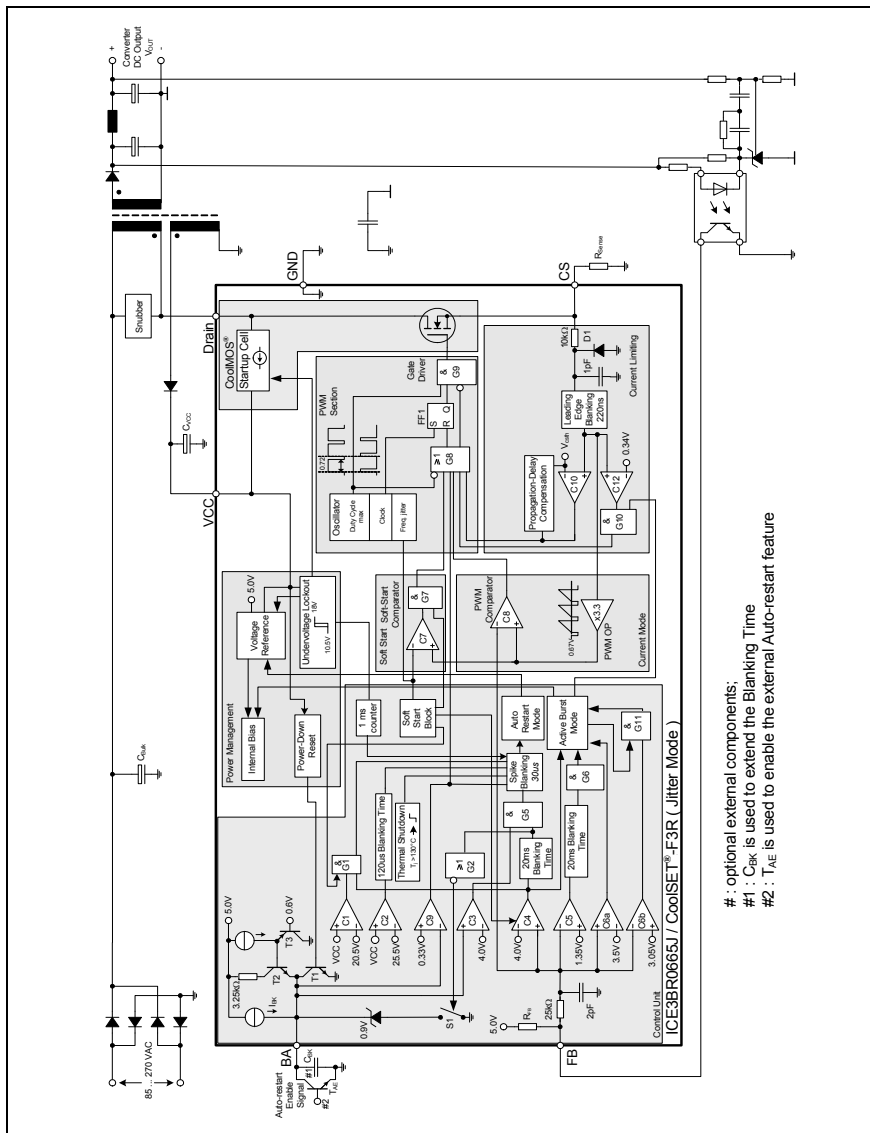


Figure 2 Representative Blockdiagram

3 Functional Description

All values which are used in the functional description are typical values. For calculating the worst cases the min/max values which can be found in section 4 Electrical Characteristics have to be considered.

3.1 Introduction

CoolSET®-F3R jitter series (ICE3BRxx65J) is the latest version of the CoolSET®-F3 for the lower power application. The particular enhanced features are the built-in features for soft start, blanking window and frequency jitter. It provides the flexibility to increase the blanking window by simply addition of a capacitor in BA pin. In order to further increase the flexibility of the protection feature, an external auto-restart enable features are added. Moreover, the proven outstanding features in CoolSET®-F3 are still remained such as the active burst mode, propagation delay compensation, modulated gate driving, auto-restart protection for V_{cc} overvoltage, over temperature, over load, open loop, etc.

The intelligent Active Burst Mode can effectively obtain the lowest Standby Power at light load and no load conditions. After entering the burst mode, there is still a full control of the power conversion to the output through the optocoupler, that is used for the normal PWM control. The response on load jumps is optimized and the voltage ripple on V_{out} is minimized. The V_{out} is on well controlled in this mode.

The usually external connected RC-filter in the feedback line after the optocoupler is integrated in the IC to reduce the external part count.

Furthermore a high voltage Startup Cell is integrated into the IC which is switched off once the Undervoltage Lockout on-threshold of 18V is exceeded. This Startup Cell is part of the integrated CoolMOS®. The external startup resistor is no longer necessary as this Startup Cell is connected to the Drain. Power losses are therefore reduced. This increases the efficiency under light load conditions drastically.

Adopting the BiCMOS technology, it can increase the design flexibility as the V_{cc} voltage range is increased to 25V.

The CoolSET®-F3R has a built-in 20ms soft start function. It can further save external component counts.

There are 2 modes of blanking time for high load jumps; the basic mode and the extendable mode. The blanking time for the basic mode is set at 20ms while the extendable mode will increase the blanking time by adding an external capacitor at the BA pin in addition to the basic mode blanking time. During this blanking time window the overload detection is disabled. With this concept no further external components are necessary to adjust the blanking window.

In order to increase the robustness and safety of the system, the IC provides Auto Restart protection. The Auto Restart Mode reduces the average power conversion to a minimum level under unsafe operating conditions. This is necessary for a prolonged fault condition which could otherwise lead to a destruction of the SMPS over time. Once the malfunction is removed, normal operation is automatically retained after the next Start Up Phase. To make the protection more flexible, an external auto-restart enable pin is provided. When the pin is triggered, the switching pulse at gate will stop and the IC enters the auto-restart mode after the pre-defined spike blanking time.

The internal precise peak current control reduces the costs for the transformer and the secondary diode. The influence of the change in the input voltage on the maximum power limitation can be avoided together with the integrated Propagation Delay Compensation. Therefore the maximum power is nearly independent on the input voltage, which is required for wide range SMPS. Thus there is no need for the over-sizing of the SMPS, e.g. the transformer and the output diode.

Furthermore, this F3R series implements the frequency jitter mode to the switching clock such that the EMI noise will be effectively reduced.

3.2 Power Management

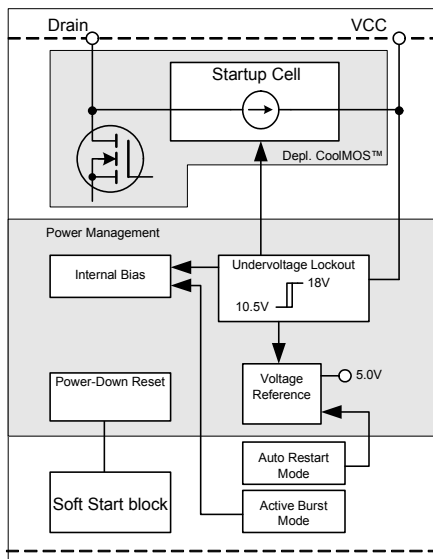


Figure 3 Power Management

Functional Description

The Undervoltage Lockout monitors the external supply voltage V_{VCC} . When the SMPS is plugged to the main line the internal Startup Cell is biased and starts to charge the external capacitor C_{VCC} which is connected to the VCC pin. This VCC charge current is controlled to 0.9mA by the Startup Cell. When the V_{VCC} exceeds the on-threshold $V_{CCon}=18V$ the bias circuit are switched on. Then the Startup Cell is switched off by the Undervoltage Lockout and therefore no power losses present due to the connection of the Startup Cell to the Drain voltage. To avoid uncontrolled ringing at switch-on, a hysteresis start up voltage is implemented. The switch-off of the controller can only take place when V_{VCC} falls below 10.5V after normal operation was entered. The maximum current consumption before the controller is activated is about 150 μ A.

When V_{VCC} falls below the off-threshold $V_{CCoff}=10.5V$, the bias circuit is switched off and the soft start counter is reset. Thus it is ensured that at every startup cycle the soft start starts at zero.

The internal bias circuit is switched off if Auto Restart Mode is entered. The current consumption is then reduced to 150 μ A.

Once the malfunction condition is removed, this block will then turn back on. The recovery from Auto Restart Mode does not require re-cycling the AC line.

When Active Burst Mode is entered, the internal Bias is switched off most of the time but the Voltage Reference is kept alive in order to reduce the current consumption below 450 μ A.

3.3 Improved Current Mode

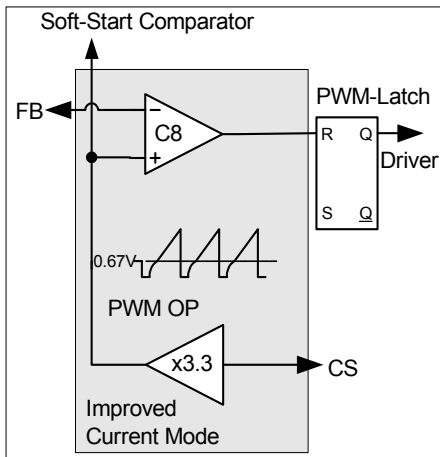


Figure 4 Current Mode

Current Mode means the duty cycle is controlled by the slope of the primary current. This is done by comparing the FB signal with the amplified current sense signal.

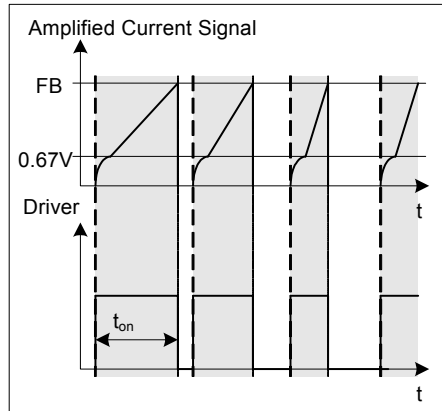


Figure 5 Pulse Width Modulation

In case the amplified current sense signal exceeds the FB signal the on-time T_{on} of the driver is finished by resetting the PWM-Latch (see Figure 5).

The primary current is sensed by the external series resistor R_{Sense} inserted in the source of the integrated CoolMOS®. By means of Current Mode regulation, the secondary output voltage is insensitive to the line variations. The current waveform slope will change with the line variation, which controls the duty cycle.

The external R_{Sense} allows an individual adjustment of the maximum source current of the integrated CoolMOS®.

To improve the Current Mode during light load conditions the amplified current ramp of the PWM-OP is superimposed on a voltage ramp, which is built by the switch T2, the voltage source V1 and a resistor R1 (see Figure 6). Every time the oscillator shuts down for maximum duty cycle limitation the switch T2 is closed by V_{OSC} . When the oscillator triggers the Gate Driver, T2 is opened so that the voltage ramp can start.

In case of light load the amplified current ramp is too small to ensure a stable regulation. In that case the Voltage Ramp is a well defined signal for the comparison with the FB-signal. The duty cycle is then controlled by the slope of the Voltage Ramp.

By means of the time delay circuit which is triggered by the inverted V_{OSC} signal, the Gate Driver is switched-off until it reaches approximately 156ns delay time (see Figure 7). It allows the duty cycle to be reduced continuously till 0% by decreasing V_{FB} below that threshold.

Functional Description

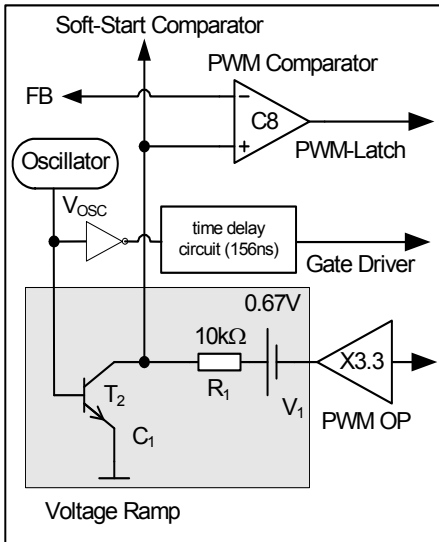


Figure 6 Improved Current Mode

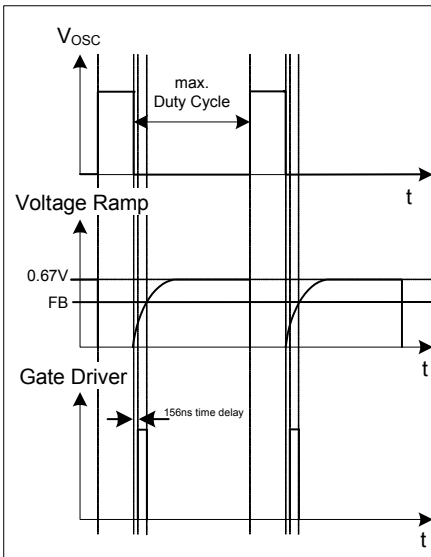


Figure 7 Light Load Conditions

3.3.1 PWM-OP

The input of the PWM-OP is applied over the internal leading edge blanking to the external sense resistor R_{Sense} connected to pin CS. R_{Sense} converts the source current into a sense voltage. The sense voltage is amplified with a gain of 3.3 by PWM OP. The output of the PWM-OP is connected to the voltage source V_1 . The voltage ramp with the superimposed amplified current signal is fed into the positive inputs of the PWM-Comparator C8 and the Soft-Start-Comparator (see Figure 6).

3.3.2 PWM-Comparator

The PWM-Comparator compares the sensed current signal of the integrated CoolMOS® with the feedback signal V_{FB} (see Figure 8). V_{FB} is created by an external optocoupler or external transistor in combination with the internal pull-up resistor R_{FB} and provides the load information of the feedback circuitry. When the amplified current signal of the integrated CoolMOS® exceeds the signal V_{FB} the PWM-Comparator switches off the Gate Driver.

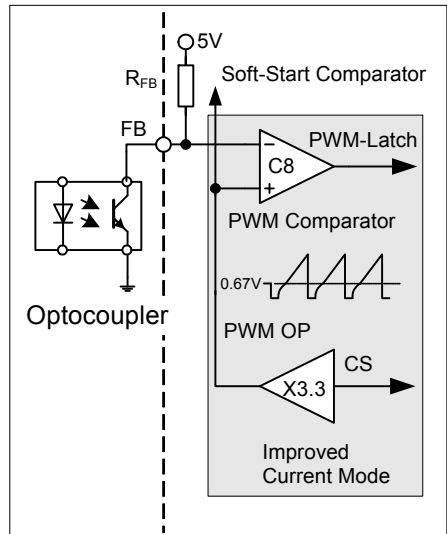


Figure 8 PWM Controlling

Functional Description

3.4 Startup Phase

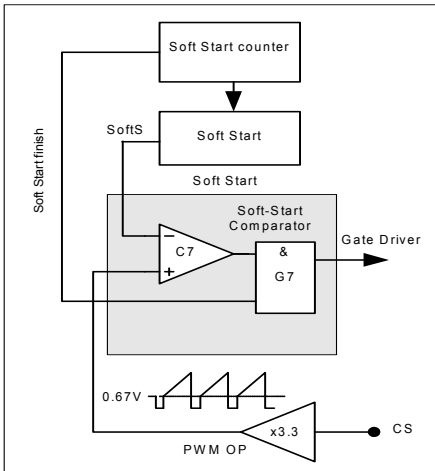


Figure 9 Soft Start

In the Startup Phase, the IC provides a Soft Start period to control the primary current by means of a duty cycle limitation. The Soft Start function is a built-in function and it is controlled by an internal counter.

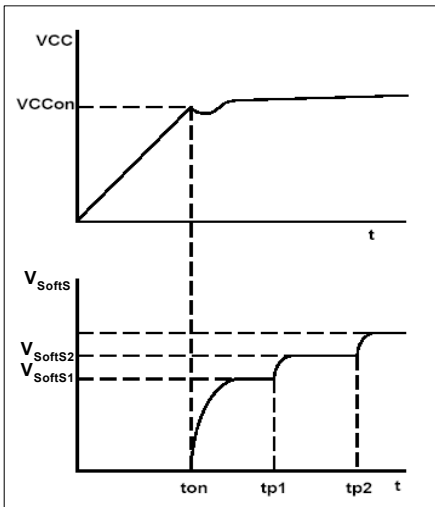


Figure 10 Soft Start Phase

When the V_{VCC} exceeds the on-threshold voltage, the IC starts the Soft Start mode (see Figure 10).

The function is realized by an internal Soft Start resistor, an current sink and a counter. And the amplitude of the current sink is controlled by the counter (see Figure 11).

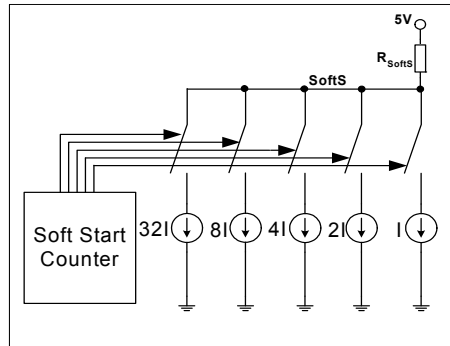


Figure 11 Soft Start Circuit

After the IC is switched on, the V_{SFOFTS} voltage is controlled such that the voltage is increased step-wisely (32 steps) with the increase of the counts. The Soft Start counter would send a signal to the current sink control in every 600us such that the current sink decrease gradually and the duty ratio of the gate drive increases gradually. The Soft Start will be finished in 20ms ($t_{Soft-Start}$) after the IC is switched on. At the end of the Soft Start period, the current sink is switched off.

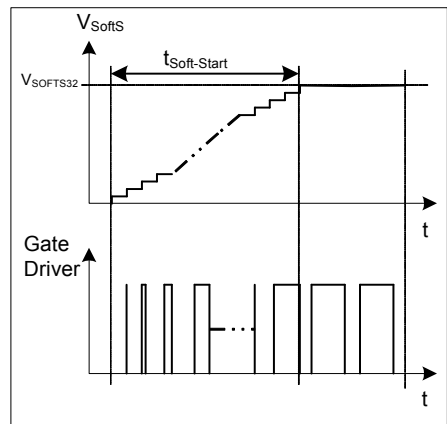


Figure 12 Gate drive signal under Soft-Start Phase

Within the soft start period, the duty cycle is increasing from zero to maximum gradually (see Figure 12).

In addition to Start-Up, Soft-Start is also activated at each restart attempt during Auto Restart.

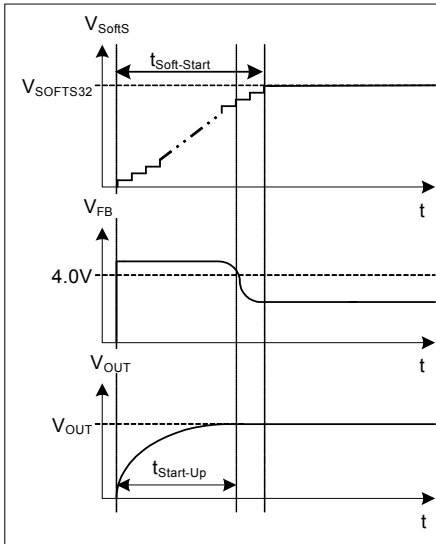


Figure 13 Start Up Phase

The Start-Up time $t_{\text{Start-Up}}$ before the converter output voltage V_{OUT} is settled, must be shorter than the Soft-Start Phase $t_{\text{Soft-Start}}$ (see Figure 13).

By means of Soft-Start there is an effective minimization of current and voltage stresses on the integrated CoolMOS®, the clamp circuit and the output overshoot and it helps to prevent saturation of the transformer during Start-Up.

3.5 PWM Section

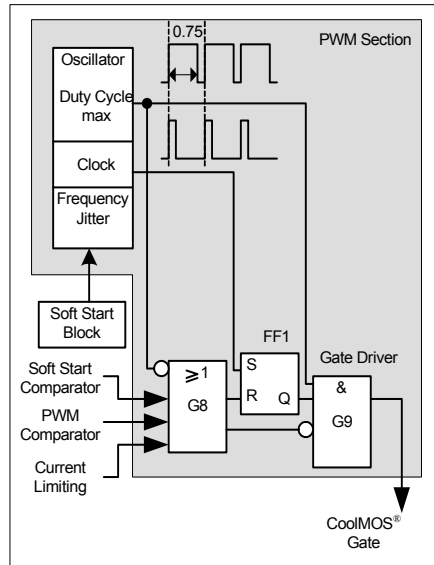


Figure 14 PWM Section Block

3.5.1 Oscillator

The oscillator generates a fixed frequency of 65KHz with frequency jittering of $\pm 4\%$ (which is $\pm 2.6\text{KHz}$) at a jittering period of 4ms.

A capacitor, a current source and current sink which determine the frequency are integrated. In order to achieve a very accurate switching frequency, the charging and discharging current of the implemented oscillator capacitor are internally trimmed. The ratio of controlled charge to discharge current is adjusted to reach a maximum duty cycle limitation of $D_{\text{max}}=0.75$.

Once the Soft Start period is over and when the IC goes into normal operating mode, the switching frequency of the clock is varied by the control signal from the Soft Start block. Then the switching frequency is varied in range of $65\text{KHz} \pm 2.6\text{KHz}$ at period of 4ms.

3.5.2 PWM-Latch FF1

The output of the oscillator block provides continuous pulse to the PWM-Latch which turns on/off the integrated CoolMOS®. After the PWM-Latch is set, it is reset by the PWM comparator, the Soft Start comparator or the Current-Limit comparator. When it is in reset mode, the output of the driver is shut down immediately.

3.5.3 Gate Driver

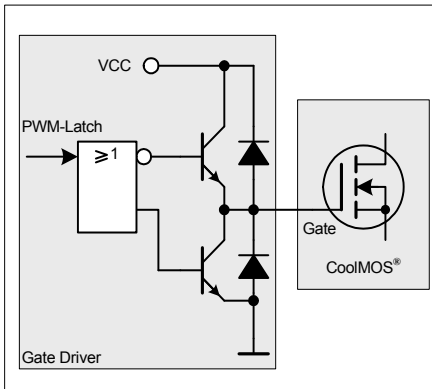


Figure 15 Gate Driver

The driver-stage is optimized to minimize EMI and to provide high circuit efficiency. The switch on speed is slowed down before it reaches the integrated CoolMOS® turn on threshold. That is a slope control of the rising edge at the output of the driver (see Figure 16).

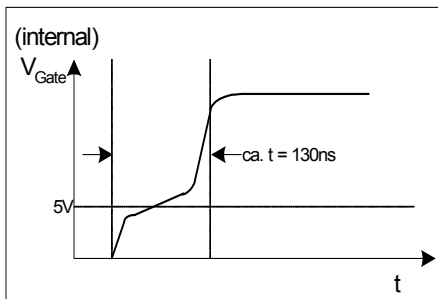


Figure 16 Gate Rising Slope

Thus the leading switch on spike is minimized. Furthermore the driver circuit is designed to eliminate cross conduction of the output stage.

During power up, when VCC is below the undervoltage lockout threshold V_{VCCoff} , the output of the Gate Driver is set to low in order to disable power transfer to the secondary side.

3.6 Current Limiting

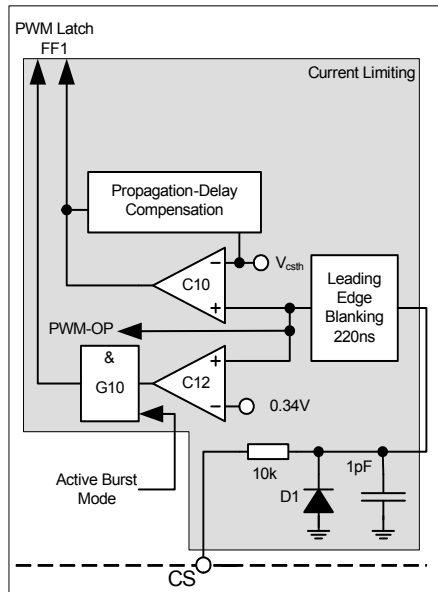


Figure 17 Current Limiting Block

There is a cycle by cycle peak current limiting operation realized by the Current-Limit comparator C10. The source current of the integrated CoolMOS® is sensed via an external sense resistor R_{sense} . By means of R_{sense} the source current is transformed to a sense voltage V_{sense} which is fed into the CS pin. If the voltage V_{sense} exceeds the internal threshold voltage V_{csth} , the comparator C10 immediately turns off the gate drive by resetting the PWM Latch FF1.

A Propagation Delay Compensation is added to support the immediate shut down of the integrated CoolMOS® with very short propagation delay. Thus the influence of the AC input voltage on the maximum output power can be reduced to minimal.

In order to prevent the current limit from distortions caused by leading edge spikes, a Leading Edge Blanking is integrated in the current sense path for the comparators C10, C12 and the PWM-OP.

The output of comparator C12 is activated by the Gate G10 if Active Burst Mode is entered. When it is activated, the current limiting is reduced to 0.34V. This voltage level determines the maximum power level in Active Burst Mode.

Functional Description

3.6.1 Leading Edge Blanking

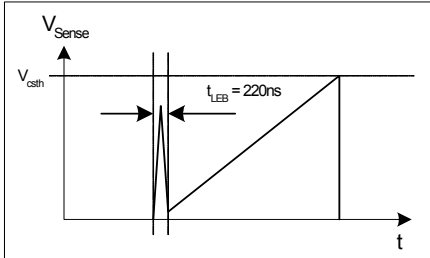


Figure 18 Leading Edge Blanking

Whenever the integrated CoolMOS® is switched on, a leading edge spike is generated due to the primary-side capacitances and reverse recovery time of the secondary-side rectifier. This spike can cause the gate drive to switch off unintentionally. In order to avoid a premature termination of the switching pulse, this spike is blanked out with a time constant of $t_{LEB} = 220\text{ns}$.

3.6.2 Propagation Delay Compensation

In case of over-current detection, there is always propagation delay to switch off the integrated CoolMOS®. An overshoot of the peak current I_{peak} is induced to the delay, which depends on the ratio of dI/dt of the peak current (see Figure 19).

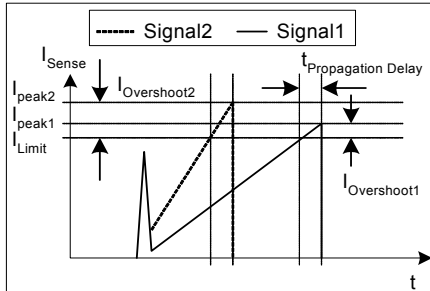


Figure 19 Current Limiting

The overshoot of Signal2 is larger than of Signal1 due to the steeper rising waveform. This change in the slope depends on the AC input voltage. Propagation Delay Compensation is integrated to reduce the overshoot due to dI/dt of the rising primary current. Thus the propagation delay time between exceeding the current sense threshold V_{csth} and the switching off of the integrated CoolMOS® is compensated over temperature within a wide range. Current Limiting is then very accurate.

For example, $I_{peak} = 0.5\text{A}$ with $R_{Sense} = 2$. The current sense threshold is set to a static voltage level $V_{csth} = 1\text{V}$ without Propagation Delay Compensation. A current ramp of $dI/dt = 0.4\text{A}/\mu\text{s}$, or $dV_{Sense}/dt = 0.8\text{V}/\mu\text{s}$, and a propagation delay time of $t_{Propagation Delay} = 180\text{ns}$ leads to an I_{peak} overshoot of 14.4%. With the propagation delay compensation, the overshoot is only around 2% (see Figure 20).

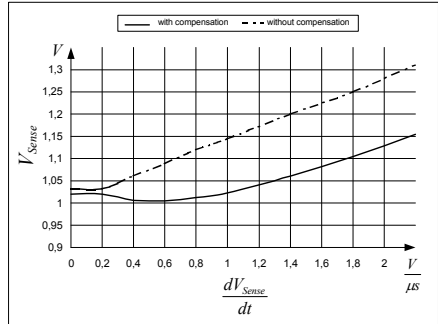


Figure 20 Overcurrent Shutdown

The Propagation Delay Compensation is realized by means of a dynamic threshold voltage V_{csth} (see Figure 21). In case of a steeper slope the switch off of the driver is earlier to compensate the delay.

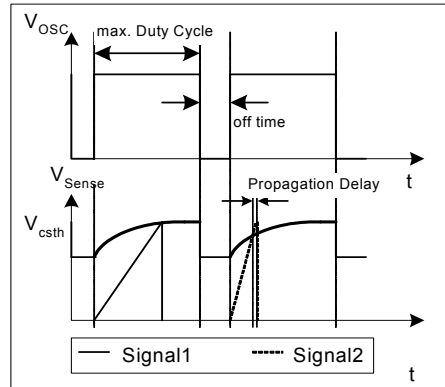


Figure 21 Dynamic Voltage Threshold V_{csth}

Functional Description

3.7 Control Unit

The Control Unit contains the functions for Active Burst Mode and Auto Restart Mode. The Active Burst Mode and the Auto Restart Mode both have 20ms internal Blanking Time. For the Auto Restart Mode, a further extendable Blanking Time is achieved by adding external capacitor at BA pin. By means of this Blanking Time, the IC avoids entering into these two modes accidentally. Furthermore those buffer time for the overload detection is very useful for the application that works in low current but requires a short duration of high current occasionally.

3.7.1 Basic and Extendable Blanking Mode

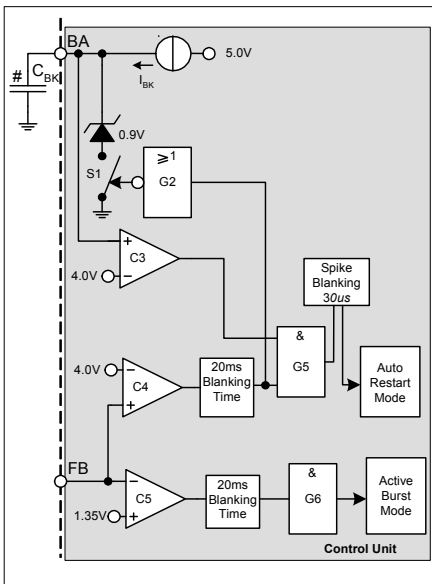


Figure 22 Basic and Extendable Blanking Mode

There are 2 kinds of Blanking mode; basic mode and the extendable mode. The basic mode is just an internal set 20ms blanking time while the extendable mode has an extra blanking time by connecting an external capacitor to the BA pin in addition to the pre-set 20ms blanking time. For the extendable mode, the gate G5 is blocked even though the 20ms blanking time is reached if an external capacitor C_{BK} is added to BA pin. While the 20ms blanking time is passed, the switch S1 is opened by G2. Then the 0.9V clamped voltage at BA pin is charged to 4.0V through the internal I_{BK} constant current. G5 is enabled by comparator C3.

After the 30us spike blanking time, the Auto Restart Mode is activated.

For example, if $C_{BK} = 0.22\mu F$, $I_{BK} = 13\mu A$

Blanking time = $20ms + C_{BK} \times (4.0 - 0.9) / I_{BK} = 72ms$

In order to make the startup properly, the maximum C_{BK} capacitor is restricted to less than 0.65uF.

The Active Burst Mode has basic blanking mode only while the Auto Restart Mode has both the basic and the extendable blanking mode.

3.7.2 Active Burst Mode

The IC enters Active Burst Mode under low load conditions. With the Active Burst Mode, the efficiency increases significantly at light load conditions while still maintaining a low ripple on V_{OUT} and a fast response on load jumps. During Active Burst Mode, the IC is controlled by the FB signal. Since the IC is always active, it can be a very fast response to the quick change at the FB signal. The Start up Cell is kept OFF in order to minimize the power loss.

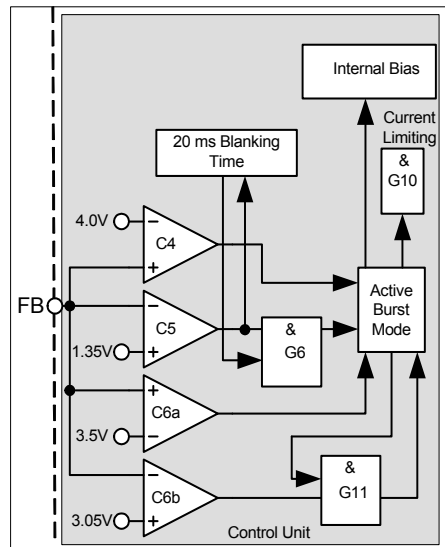


Figure 23 Active Burst Mode

The Active Burst Mode is located in the Control Unit. Figure 23 shows the related components.

3.7.2.1 Entering Active Burst Mode

The FB signal is kept monitoring by the comparator C5. During normal operation, the internal blanking time counter is reset to 0. Once the FB signal falls below 1.35V, it starts to count. When the counter reach 20ms

Functional Description

and FB signal is still below 1.35V, the system enters the Active Burst Mode. This time window prevents a sudden entering into the Active Burst Mode due to large load jumps.

After entering Active Burst Mode, a burst flag is set and the internal bias is switched off in order to reduce the current consumption of the IC to approx. 450uA.

It needs the application to enforce the VCC voltage above the Undervoltage Lockout level of 10.5V such that the Startup Cell will not be switched on accidentally. Or otherwise the power loss will increase drastically. The minimum VCC level during Active Burst Mode depends on the load condition and the application. The lowest VCC level is reached at no load condition.

3.7.2.2 Working in Active Burst Mode

After entering the Active Burst Mode, the FB voltage rises as V_{OUT} starts to decrease, which is due to the inactive PWM section. The comparator C6a monitors the FB signal. If the voltage level is larger than 3.5V, the internal circuit will be activated; the Internal Bias circuit resumes and starts to provide switching pulse. In Active Burst Mode the gate G10 is released and the current limit is reduced to 0.34V, which can reduce the conduction loss and the audible noise. If the load at V_{OUT} is still kept unchanged, the FB signal will drop to 3.05V. At this level the C6b deactivates the internal circuit again by switching off the internal Bias. The gate G11 is active again as the burst flag is set after entering Active Burst Mode. In Active Burst Mode, the FB voltage is changing like a saw tooth between 3.05V and 3.5V (see figure 24).

3.7.2.3 Leaving Active Burst Mode

The FB voltage will increase immediately if there is a high load jump. This is observed by the comparator C4. Since the current limit is app. 34% during Active Burst Mode, it needs a certain load jump to rise the FB signal to exceed 4.0V. At that time the comparator C4 resets the Active Burst Mode control which in turn blocks the comparator C12 by the gate G10. The maximum current can then be resumed to stabilize the V_{OUT} .

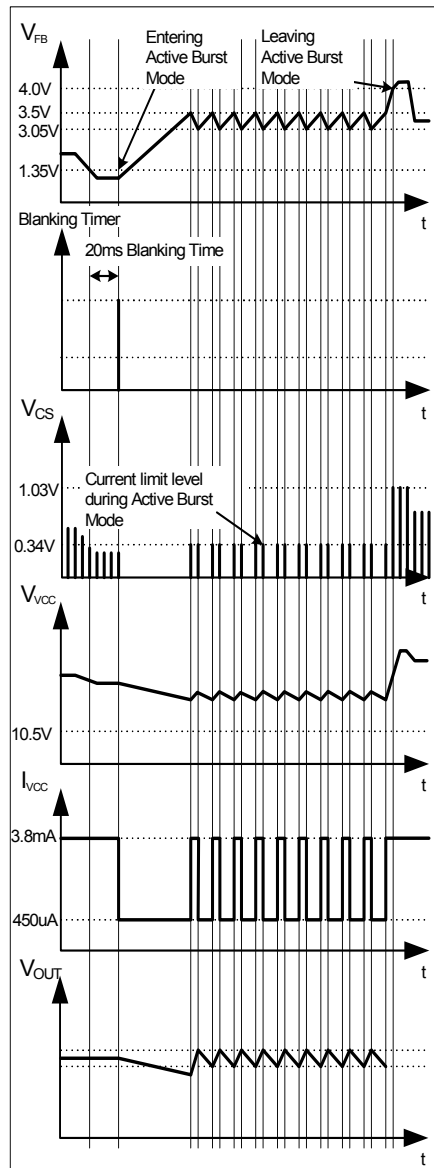


Figure 24 Signals in Active Burst Mode

Functional Description

3.7.3 Protection Modes

The IC provides Auto Restart Mode as the protection feature. Auto Restart mode can prevent the SMPS from destructive states. The following table shows the relationship between possible system failures and the corresponding protection modes.

VCC Overvoltage	Auto Restart Mode
Overtemperature	Auto Restart Mode
Overload	Auto Restart Mode
Open Loop	Auto Restart Mode
VCC Undervoltage	Auto Restart Mode
Short Optocoupler	Auto Restart Mode
Auto restart enable	Auto Restart Mode

Before entering the Auto Restart protection mode, some of the protections can have extended blanking time to delay the protection and some needs to fast react and will go straight to the protection. Overload and open loop protection are the one can have extended blanking time while Vcc Overvoltage, Over temperature, Vcc Undervoltage, short opto-coupler and external auto restart enable will go to protection right away.

After the system enters the Auto-restart mode, the IC will be off. Since there is no more switching, the Vcc voltage will drop. When it hits the Vcc turn off threshold, the start up cell will turn on and the Vcc is charged by the startup cell current to Vcc turn on threshold. The IC is on and the startup cell will turn off. At this stage, it will enter the startup phase (soft start) with switching cycles. After the Start Up Phase, the fault condition is checked. If the fault condition persists, the IC will go to auto restart mode again. If, otherwise, the fault is removed, normal operation is resumed.

3.7.3.1 Auto Restart mode with extended blanking time

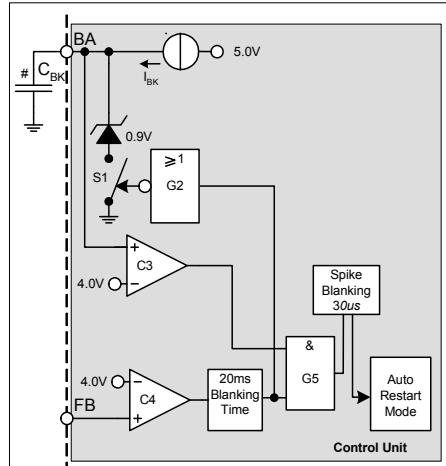


Figure 25 Auto Restart Mode

In case of Overload or Open Loop, the FB exceeds 4.0V which will be observed by comparator C4. Then the internal blanking counter starts to count. When it reaches 20ms, the switch S1 is released. Then the clamped voltage 0.9V at V_{BA} can increase. When there is no external capacitor C_{BK} connected, the V_{BA} will reach 4.0V immediately. When both the input signals at AND gate G5 is positive, the Auto Restart Mode will be activated after the extra spike blanking time of 30us elapsed. However, when an extra blanking time is needed, it can be achieved by adding an external capacitor, C_{BK}. A constant current source of I_{BK} will start to charge the capacitor C_{BK} from 0.9V to 4.0V after the switch S1 is released. The charging time from 0.9V to 4.0V are the extendable blanking time. If C_{BK} is 0.22uF and I_{BK} is 13uA, the extendable blanking time is around 52ms and the total blanking time is 72ms. In combining the FB and blanking time, there is a blanking window generated which prevents the system to enter Auto Restart Mode due to large load jumps.

Functional Description

3.7.3.2 Auto Restart without extended blanking time

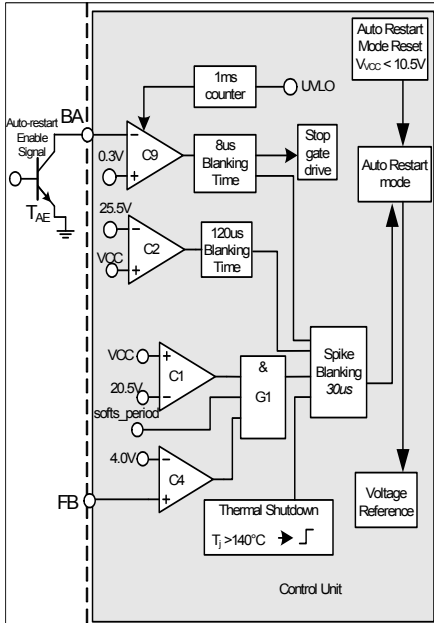


Figure 26 Auto Restart mode

There are 2 modes of V_{CC} overvoltage protection; one is during soft start and the other is at all conditions.

The first one is V_{VCC} voltage is $> 20.5V$ and FB is $> 4.0V$ and during soft start period and the IC enters Auto Restart Mode. The VCC voltage is observed by comparator C1 and C4. The fault conditions are to detect the abnormal operating during start up such as open loop during light load start up, etc. The logic can eliminate the possible of entering Auto Restart mode if there is a small voltage overshoots of V_{VCC} during normal operating.

The 2nd one is $V_{VCC} > 25.5V$ and last for 120 μs and the IC enters Auto Restart Mode. This 25.5V V_{CC} OVP protection is inactivated during burst mode.

The Thermal Shutdown block monitors the junction temperature of the IC. After detecting a junction temperature higher than 130°C, the Auto Restart Mode is entered.

In case the pre-defined auto-restart features are not sufficient, there is a customer defined external Auto-restart Enable feature. This function can be triggered by pulling down the BA pin to $< 0.33V$. It can simply add

a trigger signal to the base of the externally added transistor, T_{AE} at the BA pin. When the function is enabled, the gate drive switching will be stopped and then the IC will enter auto-restart mode if the signal persists. To ensure this auto-restart function will not be mis-triggered during start up, a 1ms delay time is implemented to blank the unstable signal.

VCC undervoltage is the Vcc voltage drop below Vcc turn off threshold. Then the IC will turn off and the start up cell will turn on automatically. And this leads to Auto Restart Mode.

Short Optocoupler also leads to VCC undervoltage as there is no self supply after activating the internal reference and bias.

4 Electrical Characteristics

Note: All voltages are measured with respect to ground (Pin 5). The voltage levels are valid if other ratings are not violated.

4.1 Absolute Maximum Ratings

Note: Absolute maximum ratings are defined as ratings, which when being exceeded may lead to destruction of the integrated circuit. For the same reason make sure, that any capacitor that will be connected to pin 4 (V_{CC}) is discharged before assembling the application circuit. T_a=25°C unless otherwise specified.

Parameter	Symbol	Limit Values		Unit	Remarks
		min.	max.		
Switching drain current, pulse width t _p limited by T _J =150°C	I _s	-	9.95	A	
Pulse drain current, pulse width t _p limited by T _J =150°C	I _{D_Puls}	-	15.75	A	
Avalanche energy, repetitive t _{AR} limited by max. T _J =150°C ¹⁾	E _{AR}	-	0.47	mJ	
Avalanche current, repetitive t _{AR} limited by max. T _J =150°C ¹⁾	I _{AR}	-	2.5	A	
VCC Supply Voltage	V _{VCC}	-0.3	27	V	
FB Voltage	V _{FB}	-0.3	5.5	V	
BA Voltage	V _{BA}	-0.3	5.5	V	
CS Voltage	V _{CS}	-0.3	5.5	V	
Junction Temperature	T _J	-40	150	°C	Controller & CoolMOS®
Storage Temperature	T _S	-55	150	°C	
Thermal Resistance Junction -Ambient	R _{thJA}	-	90	K/W	
Soldering temperature, wavesoldering only allowed at leads	T _{sold}	-	260	°C	1.6mm (0.063in.) from case for 10s
ESD Capability (incl. Drain Pin)	V _{ESD}	-	2	kV	Human body model ²⁾

¹⁾ Repetitive avalanche causes additional power losses that can be calculated as P_{AV}=E_{AR}*f

²⁾ According to EIA/JESD22-A114-B (discharging a 100pF capacitor through a 1.5kΩ series resistor)

Electrical Characteristics

4.2 Operating Range

Note: Within the operating range the IC operates as described in the functional description.

Parameter	Symbol	Limit Values		Unit	Remarks
		min.	max.		
VCC Supply Voltage	V_{VCC}	V_{VCCoff}	25	V	Max value limited due to Vcc OVP
Junction Temperature of Controller	T_{Jcon}	-25	130	°C	Max value limited due to thermal shut down of controller
Junction Temperature of CoolMOS®	$T_{JCoolMOS}$	-25	150	°C	

4.3 Characteristics

4.3.1 Supply Section

Note: The electrical characteristics involve the spread of values within the specified supply voltage and junction temperature range T_J from -25 °C to 125 °C. Typical values represent the median values, which are related to 25°C. If not otherwise stated, a supply voltage of $V_{CC} = 18\text{ V}$ is assumed.

Parameter	Symbol	Limit Values			Unit	Test Condition
		min.	typ.	max.		
Start Up Current	$I_{VCCstart}$	-	150	250	μA	$V_{VCC} = 17\text{V}$
VCC Charge Current	$I_{VCCcharge1}$	-	-	5.0	mA	$V_{VCC} = 0\text{V}$
	$I_{VCCcharge2}$	0.55	0.9	1.60	mA	$V_{VCC} = 1\text{V}$
	$I_{VCCcharge3}$	-	0.7	-	mA	$V_{VCC} = 17\text{V}$
Leakage Current of Start Up Cell and CoolMOS®	$I_{StartLeak}$	-	0.2	50	μA	$V_{Drain} = 450\text{V}$ at $T_J = 100^\circ\text{C}$
Supply Current with Inactive Gate	$I_{VCCsup1}$	-	1.5	2.5	mA	
Supply Current with Active Gate	$I_{VCCsup2}$	-	3.8	4.2	mA	$I_{FB} = 0\text{A}$
Supply Current in Auto Restart Mode with Inactive Gate	$I_{VCCrestart}$	-	250	-	μA	$I_{FB} = 0\text{A}$
Supply Current in Active Burst Mode with Inactive Gate	$I_{VCCburst1}$	-	450	950	μA	$V_{FB} = 2.5\text{V}$
	$I_{VCCburst2}$	-	450	950	μA	$V_{VCC} = 11.5\text{V}, V_{FB} = 2.5\text{V}$
VCC Turn-On Threshold	V_{VCCon}	17.0	18.0	19.0	V	
VCC Turn-Off Threshold	V_{VCCoff}	9.8	10.5	11.2	V	
VCC Turn-On/Off Hysteresis	V_{VCChys}	-	7.5	-	V	

Electrical Characteristics
4.3.2 Internal Voltage Reference

Parameter	Symbol	Limit Values			Unit	Test Condition
		min.	typ.	max.		
Trimmed Reference Voltage	V_{REF}	4.90	5.00	5.10	V	measured at pin FB $I_{FB} = 0$

4.3.3 PWM Section

Parameter	Symbol	Limit Values			Unit	Test Condition
		min.	typ.	max.		
Fixed Oscillator Frequency	f_{OSC1}	56.5	65.0	73.5	kHz	
	f_{OSC2}	59.8	65.0	70.2	kHz	$T_j = 25^\circ\text{C}$
Frequency Jittering Range	f_{jitter}	-	± 2.6	-	kHz	$T_j = 25^\circ\text{C}$
Frequency Jittering period	T_{jitter}	-	4.0	-	ms	$T_j = 25^\circ\text{C}$
Max. Duty Cycle	D_{max}	0.70	0.75	0.80		
Min. Duty Cycle	D_{min}	0	-	-		$V_{FB} < 0.3\text{V}$
PWM-OP Gain	A_V	3.1	3.3	3.5		
Voltage Ramp Offset	$V_{Offset-Ramp}$	-	0.67	-	V	
V_{FB} Operating Range Min Level	V_{FBmin}	-	0.5	-	V	
V_{FB} Operating Range Max level	V_{FBmax}	-	-	4.3	V	CS=1V, limited by Comparator C4 ¹⁾
FB Pull-Up Resistor	R_{FB}	9	15.4	22	k Ω	

¹⁾ The parameter is not subjected to production test - verified by design/characterization

4.3.4 Soft Start time

Parameter	Symbol	Limit Values			Unit	Test Condition
		min.	typ.	max.		
Soft Start time	t_{SS}	-	20.0	-	ms	

Electrical Characteristics
4.3.5 Control Unit

Parameter	Symbol	Limit Values			Unit	Test Condition
		min.	typ.	max.		
Clamped V_{BA} voltage during Normal Operating Mode	V_{BAclmp}	0.85	0.9	0.95	V	$V_{FB} = 4V$
Blanking time voltage limit for Comparator C3	V_{BKC3}	3.85	4.00	4.15	V	
Over Load & Open Loop Detection Limit for Comparator C4	V_{FBC4}	3.85	4.00	4.15	V	
Active Burst Mode Level for Comparator C5	V_{FBC5}	1.25	1.35	1.45	V	
Active Burst Mode Level for Comparator C6a	V_{FBC6a}	3.35	3.50	3.65	V	After Active Burst Mode is entered
Active Burst Mode Level for Comparator C6b	V_{FBC6b}	2.93	3.05	3.16	V	After Active Burst Mode is entered
Overvoltage Detection Limit for Comparator C1	$V_{VCCOVP1}$	19.5	20.5	21.5	V	$V_{FB} = 5V$
Overvoltage Detection Limit for Comparator C2	$V_{VCCOVP2}$	25.0	25.5	26.5	V	
Auto-restart Enable level at BA pin	V_{AE}	0.25	0.33	0.4	V	$>30\mu s$
Charging current at BA pin	I_{BK}	10	13.0	16.9	μA	Charge starts after the built-in 20ms blanking time elapsed
Thermal Shutdown ¹⁾	T_{JSD}	130	140	150	$^{\circ}C$	Controller
Built-in Blanking Time for Overload Protection or enter Active Burst Mode	t_{BK}	-	20	-	ms	without external capacitor at BA pin
Inhibit Time for Auto-Restart enable function during start up	t_{IHAE}	-	1.0	-	ms	Count when $V_{CC} > 18V$
Spike Blanking Time before Auto-Restart Protection	t_{Spike}	-	30	-	μs	

¹⁾ The parameter is not subjected to production test - verified by design/characterization. The thermal shutdown temperature refers to the junction temperature of the controller.

Note: The trend of all the voltage levels in the Control Unit is the same regarding the deviation except V_{VCCOVP} .

Electrical Characteristics

4.3.6 Current Limiting

Parameter	Symbol	Limit Values			Unit	Test Condition
		min.	typ.	max.		
Peak Current Limitation (incl. Propagation Delay)	V_{csth}	0.96	1.03	1.10	V	$dV_{sense} / dt = 0.6V/\mu s$ (see Figure 20)
Peak Current Limitation during Active Burst Mode	V_{CS2}	0.29	0.34	0.38	V	
Leading Edge Blanking	t_{LEB}	-	220	-	ns	
CS Input Bias Current	I_{CSbias}	-1.5	-0.2	-	μA	$V_{CS} = 0V$

4.3.7 CoolMOS® Section

Parameter	Symbol	Limit Values			Unit	Test Condition
		min.	typ.	max.		
Drain Source Breakdown Voltage	$V_{(BR)DSS}$	650	-	-	V	$T_j = 110^\circ C$ Refer to Figure 30 for other $V_{(BR)DSS}$ in different T_j
Drain Source On-Resistance	R_{DSon}	- -	0.65 1.37	0.75 1.58	Ω Ω	$T_j = 25^\circ C$ $T_j = 125^\circ C^{1)}$ at $I_D = 2.5A$
Effective output capacitance, energy related	$C_{o(er)}$	-	26	-	pF	$V_{DS} = 0V$ to $480V^{1)}$
Rise Time	t_{rise}	-	$30^{2)}$	-	ns	
Fall Time	t_{fall}	-	$30^{2)}$	-	ns	

¹⁾ The parameter is not subjected to production test - verified by design/characterization

²⁾ Measured in a Typical Flyback Converter Application

Typical CoolMOS® Performance Characteristic

5 Typical CoolMOS® Performance Characteristic

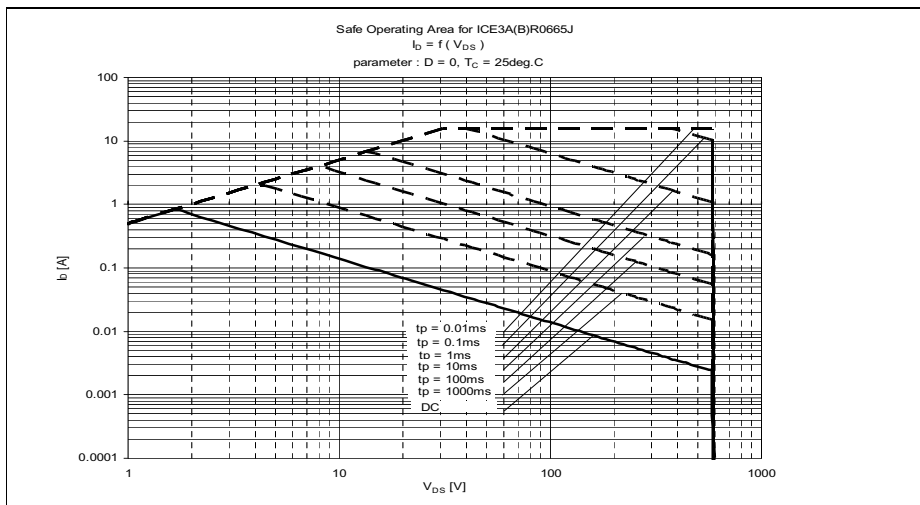


Figure 27 Safe Operating area (SOA) curve for ICE3BR0665J

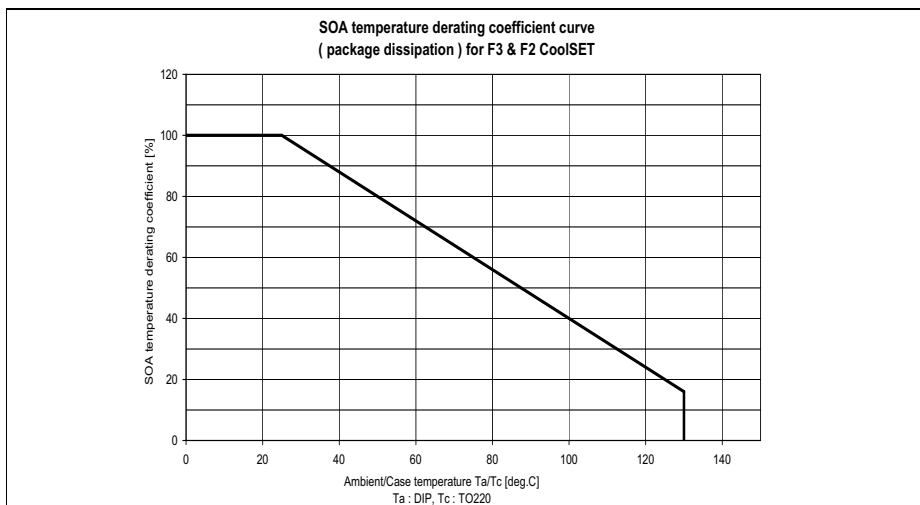


Figure 28 SOA temperature derating coefficient curve

Typical CoolMOS® Performance Characteristic

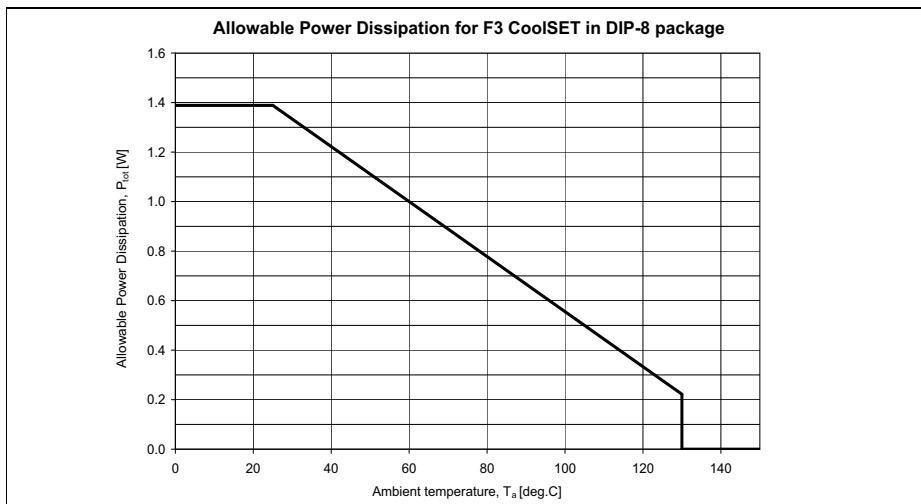


Figure 29 Power dissipation; $P_{tot}=f(T_a)$

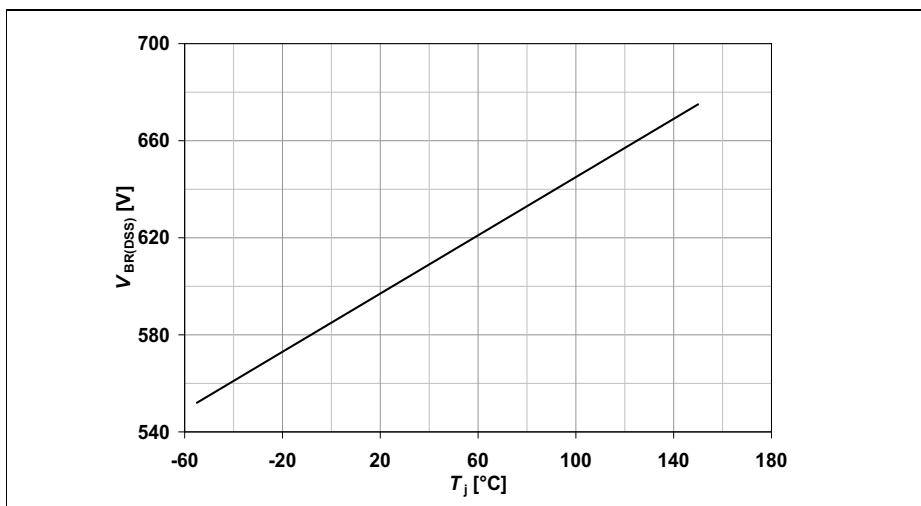


Figure 30 Drain-source breakdown voltage; $V_{BR(DSS)}=f(T_j)$

6 Input Power Curve

Two input power curves giving the typical input power versus ambient temperature are shown below; $V_{in}=85V_{ac}\sim 265V_{ac}$ (Figure 31) and $V_{in}=230V_{ac}\pm 15\%$ (Figure 32). The curves are derived based on a typical discontinuous mode flyback model which considers either 50% maximum duty ratio or 100V maximum secondary to primary reflected voltage (higher priority). The calculation is based on no copper area as heatsink for the device. The input power already includes the power loss at input common mode choke, bridge rectifier and the CoolMOS. The device saturation current (I_{D_Puls} @ $T_J=125^{\circ}C$) is also considered.

To estimate the output power of the device, it is simply multiplying the input power at a particular operating ambient temperature with the estimated efficiency for the application. For example, a wide range input voltage (Figure 31), operating temperature is $50^{\circ}C$, estimated efficiency is 85%, then the estimated output power is 42W ($49W \cdot 85\%$).

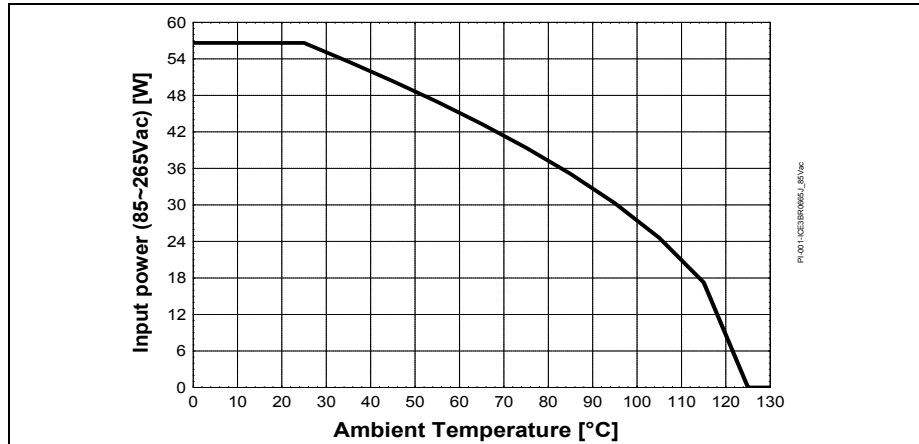


Figure 31 Input power curve $V_{in}=85\sim 265V_{ac}$; $P_{in}=f(T_a)$

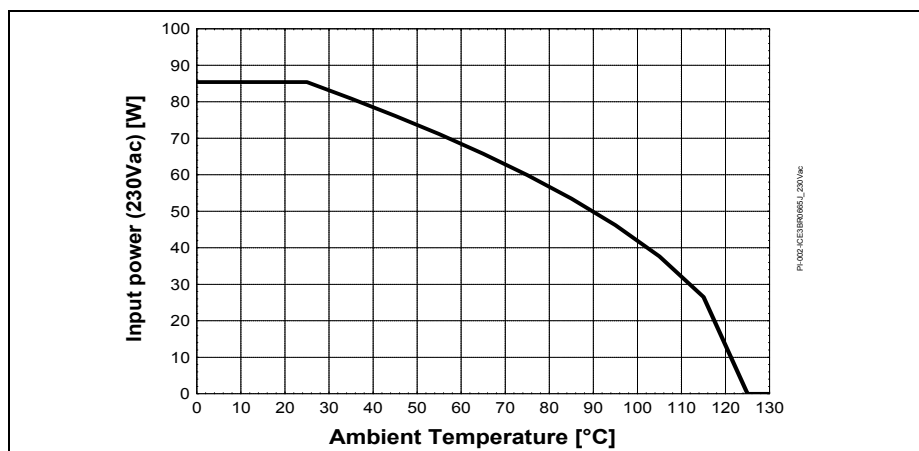


Figure 32 Input power curve $V_{in}=230V_{ac}\pm 15\%$; $P_{in}=f(T_a)$

7 Outline Dimension

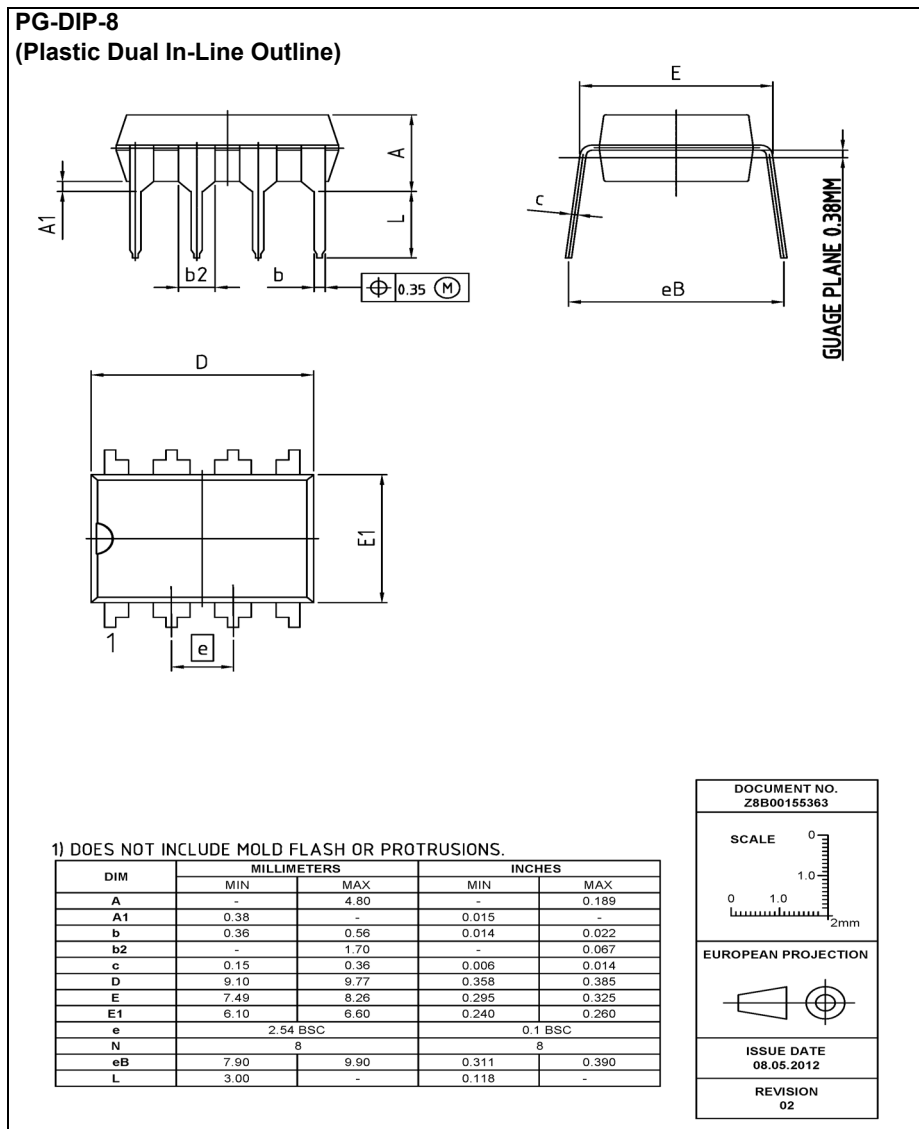


Figure 33 PG-DIP-8 (Pb-free lead plating Plastic Dual-in-Line Outline)

8 Marking

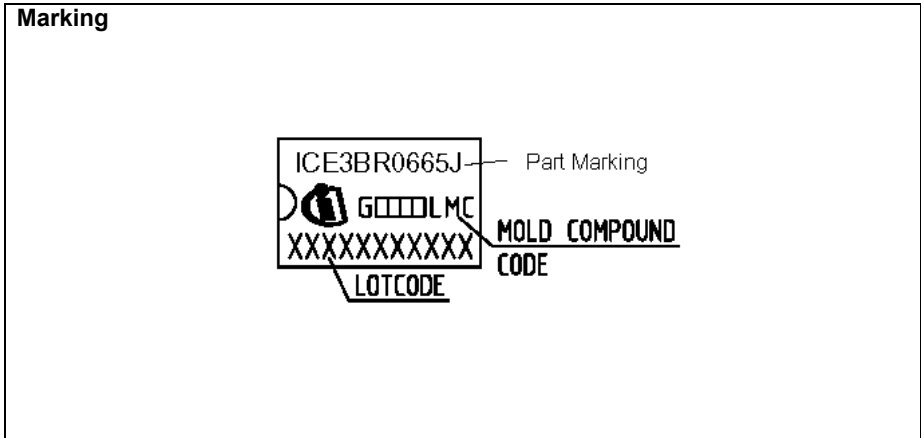


Figure 34 Marking for ICE3BR0665J

Schematic for recommended PCB layout**b. Spark Gap 1 and Spark Gap 2, Live / Neutral to GROUND:**

These 2 Spark Gaps can be used when the lightning surge requirement is >6KV.

230Vac input voltage application, the gap separation is around 5.5mm

115Vac input voltage application, the gap separation is around 3mm

2. Add Y-capacitor (C2 and C3) in the Live and Neutral to ground even though it is a 2-pin input**3. Add negative pulse clamping diode, D11 to the Current sense resistor, R12:**

The negative pulse clamping diode can reduce the negative pulse going into the CS pin of the CoolSET® and reduce the abnormal behavior of the CoolSET®. The diode can be a fast speed diode such as IN4148.

The principle behind is to drain the high surge voltage from Live/Neutral to Ground without passing through the sensitive components such as the primary controller, IC11.

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